

## Field Programmable Crystal Oscillator

Series:CPPD

### Features

- Programmed in the field with the PG-3200 oscillator programming instrument within seconds.
- Factory Programmable
- Standard Package Options

### Applications

Driving A/Ds, D/As, FPGAs  
 Digital Video  
 Ethernet, GbE  
 Medical  
 Storage Area Networking  
 COTS  
 Broad Band Access  
 SONET/ SDH/ DWDM  
 Test & Measurement



**MSL: 1**

### Part Numbering Example:

SERIES	OUTPUT	PACKAGE STYLE	VOLTAGE	ADDED FEATURES	OPERATING TEMP.	STABILITY	FREQUENCY	FREQUENCY
CPPD	C=CMOS	1 = Full Size	Blank=5.0V	Blank=Cut Tape	Blank=0°C ~ +70°C	B6=±100ppm	0.500~133.000MHz	0.500~133.000MHz
	T=TTL	4 = Half Size	L=3.3V	B=Bulk	A3=-55°C ~ +125°C	BP=±50ppm	Pin 1 Logic "0"	Pin 1 Logic "1"
		5 = 5X3.2 Ceramic	R=2.7V	T=Tube	A5=-20°C ~ +70°C	BR=±25ppm		
		7 = 5X7 Ceramic		Z=Tape and Reel	A7=-40°C ~ +85°C			

### Specifications:

Description	Min	Typ	Max	Unit
<b>Frequency Range:</b> Programmable to any discrete frequency	0.500		133	MHz
<b>Available Stability Options:</b>	-100 -50 -25		+100 +50 +25	PPM
<b>Programmable Supply Voltage:</b>	(1-133 MHz) (1-100 MHz) (1-66.0 MHz)	4.5 3.0 2.5	5.0 3.3 2.7	V V V
<b>Operating Temperature Range Options:</b>	-55 -20 -40		+125 +70 +85	°C °C °C
<b>Storage Temperature:</b>	-55		+125	°C
<b>Aging:</b> Ta=°25C,Vdd=5V/3.3V	1st year		±5	PPM/Year

**Programmable Output Level:**

CMOS/TTL

### Operating Conditions:

Description	Min	Max	Unit
<b>V<sub>DD</sub></b> Supply Voltage	2.5	5.5	V
<b>C<sub>TTL</sub></b> Max capacitive load on outputs for TTL levels 4.5V-5.5V V <sub>DD</sub> , ≤ 40 MHz 4.5V-5.5V V <sub>DD</sub> , 40 - 133 MHz		50 25	pF pF
<b>C<sub>CMOS</sub></b> Max capacitive load on outputs for CMOS levels 4.5V-5.5V V <sub>DD</sub> , ≤ 66 MHz 4.5V-5.5V V <sub>DD</sub> , 66 - 133 MHz 3.0V-3.6V V <sub>DD</sub> , ≤ 40 MHz 3.0V-3.6V V <sub>DD</sub> , 40 - 100 MHz 2.5-3.0V V <sub>DD</sub> , ≤ 66 MHz		50 25 30 15 25	pF pF pF pF pF



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**Output Clock Switching Characteristics:**

Description	Test Conditions	Min	Typ	Max	Unit
<b>Duty Cycle:</b> TTL @ 1.4V 4.5-5.5 V <sub>DD</sub>	≤ 50 MHz, C <sub>L</sub> = 50 pF	45	-	55	%
	50 - 66 MHz, C <sub>L</sub> = 15 pF	45	-	55	%
	66 - 125 MHz, C <sub>L</sub> = 25 pF	40	-	60	%
	125 - 133 MHz, C <sub>L</sub> = 15 pF	40	-	60	%
<b>Duty Cycle:</b> CMOS @ V <sub>DD</sub> /2 4.5-5.5 V <sub>DD</sub> 3.0-3.6 V <sub>DD</sub>	≤ 66 MHz, C <sub>L</sub> ≤ 25 pF	45	-	55	%
	66 - 125 MHz, C <sub>L</sub> ≤ 25 pF	40	-	60	%
	125 - 133 MHz, C <sub>L</sub> ≤ 15 pF	60	-	60	%
	≤ 40 MHz, C <sub>L</sub> ≤ 30 pF	45	-	55	%
	40 - 100 MHz, C <sub>L</sub> ≤ 15 pF	40	-	60	%
<b>Rise/Fall:</b>	0.8V - 2.0V, 4.5 - 5.5 V <sub>DD</sub> , C <sub>L</sub> = 50 pF			1.8	ns
	0.8V - 2.0V, 4.5 - 5.5 V <sub>DD</sub> , C <sub>L</sub> = 25 pF			1.2	ns
	0.8V - 2.0V, 4.5 - 5.5 V <sub>DD</sub> , C <sub>L</sub> = 15 pF			0.9	ns
	0.2V - 0.8 * V <sub>DD</sub> , 4.5 - 5.5 V <sub>DD</sub> , C <sub>L</sub> = 50 pF			3.4	ns
	0.2V - 0.8 * V <sub>DD</sub> , 3.0 - 3.6 V <sub>DD</sub> , C <sub>L</sub> = 30 pF			4.0	ns
	0.2V - 0.8 * V <sub>DD</sub> , 3.0 - 3.6 V <sub>DD</sub> , C <sub>L</sub> = 15 pF			2.4	ns
<b>Start Up Time</b>	From Power On	-	-	10	ms
<b>RMS Period Jitter</b>	1 - 133.00 MHz		8	11	ps
<b>Peak to Peak*</b>	≤ 33.000 MHz		65	99	ps
	> 33.000 MHz		65	80	ps

\* Jitter Tested at > 1,000,000 samples, exceeding JEDEC std JESD65

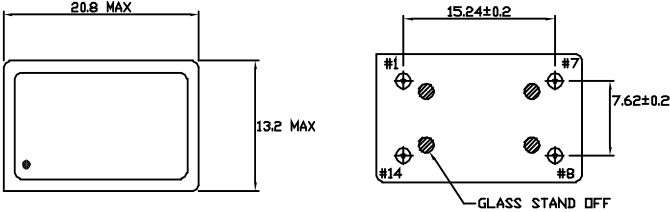
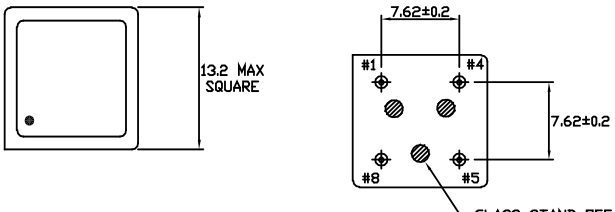
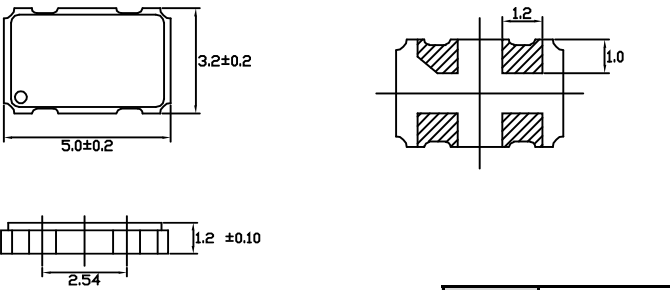
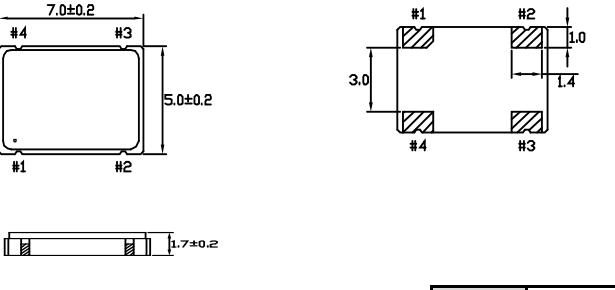
**Field Programmable Crystal Oscillator**
**Series:CPPD**
**Electrical Characteristics:**

Description	Test Conditions	Min	Typ	Max	Unit
<b>Input Characteristics (Pin 1):</b>					
V <sub>IL</sub> , Low-Level Input Voltage (To Tri-State or Power Down)	V <sub>DD</sub> = 5.0 V	-	-	0.8	V
	V <sub>DD</sub> = 3.3 V	-	-	0.2 * V <sub>DD</sub>	V
	V <sub>DD</sub> = 2.7 V	-	-	0.2 * V <sub>DD</sub>	V
V <sub>IH</sub> , High-Level Input Voltage (To Enable Output or Open)	V <sub>DD</sub> = 5.0 V	2.0	-	-	V
	V <sub>DD</sub> = 3.3 V	0.7 * V <sub>DD</sub>	-	-	V
I <sub>IL</sub> , Input Low Current	V <sub>IN</sub> = 0 V	-	-	10	μA
I <sub>IH</sub> , Input High Current	V <sub>IN</sub> = V <sub>DD</sub>	-	-	5	μA
<b>Output Characteristics:</b>					
V <sub>OL</sub> , Low-Level Output Voltage	V <sub>DD</sub> = 5.0 V, I <sub>OL</sub> = 16mA	-	-	0.4	V
	V <sub>DD</sub> = 3.3 V, I <sub>OL</sub> = 8mA	-	-	0.4	V
V <sub>IHTTL</sub> , High-Level Output Voltage	V <sub>DD</sub> = 5.0 V, I <sub>OL</sub> = -16mA	2.4	-	-	V
V <sub>IHCMOS</sub> , High-Level Output Voltage	V <sub>DD</sub> = 5.0 V, I <sub>OL</sub> = -16mA	V <sub>DD</sub> -0.4	-	-	V
	V <sub>DD</sub> = 3.3 V, I <sub>OL</sub> = -8mA	V <sub>DD</sub> -0.4	-	-	V
<b>Power Supply Current:</b> (Unloaded)	V <sub>DD</sub> = 5.0 V, F <sub>O</sub> ≤ 133 MHz	-	-	45	mA
	V <sub>DD</sub> = 3.3 V, F <sub>O</sub> ≤ 100 MHz	-	-	25	mA
	V <sub>DD</sub> = 2.7 V, F <sub>O</sub> ≤ 66.0 MHz	-	-	20	mA
<b>Standby Current:</b>		-	10	50	μA
<b>Tri-State Leakage Current</b>	V <sub>DD</sub> = 5.0 V	-	20	-	μA
<b>Output Enable Mode:</b>	Output is Tri-Stated				
<b>Power Down Mode:</b>	Output is Tri-Stated				

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\*Note: **REQUIRED** Bypass  $V_{DD}$  to GND with a  $0.01\mu\text{F}$  capacitor

Style 1 Full Size 14 pin DIP	Style 4 Half Size 8 pin DIP																				
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